

Experimental Demonstration of All-optical Flip-flop operation with a single Distributed Feedback Laser Diode

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Abstract: Dynamic all-optical flip-flop operation is observed for a single distributed feedback laser diode using the spatial hole burning effect. Bistabilities with extinction ratios of up to 35 dB are obtained. For the flip-flop operation, we demonstrate repetition rates up to 1.25 GHz using pulses of 0.5 pJ.

Keywords: All-optical flip-flop, Distributed feedback laser, Optical bistability

1. Introduction

Due to the increasing need for fast and agile networks, packet-switched optical networks draw more and more attention [1]. All-optical flip-flops offer one of the main functionalities in realizing these networks by acting as temporary memory elements which store the header information while the payload is routed to the output port. Flip-flops are designed as bistable elements with the ability to switch between the two states by using positive optical pulses. Several designs for optical flip-flops have been proposed so far, however they are often relatively complex and/or slow [2,3]. Here we report on the experimental demonstration of a novel design for an all-optical flip-flop based on a single Distributed FeedBack (DFB) laser diode [4].

By injecting continuous wave (CW) light – with a different wavelength than the lasing light – into a DFB laser diode, a bistability can occur due to a non-uniform distribution of the carriers (i.e. spatial hole burning effect). Moreover switching by using optical pulses is possible, resulting in all-optical flip-flop operation with repetition rates up to 1.25 GHz and for pulses with energy below 0.5 pJ.

2. Paper format

The bistability we observe when injecting CW-light into a DFB-laser arises from the strong influence of the carrier distribution on the threshold characteristics for lasing. In one of the states the laser is lasing and the injected light experiences a weak amplification due to gain clamping. In the other state the injected light is strongly amplified resulting in a non-uniform distribution of the carriers. This effect is called spatial hole-burning and increases the threshold for lasing, causing the laser to switch off. Therefore all the injected carriers in the device are used to amplify the injected light.

The bistability can be exploited for all-optical flip-flop operation (Figure 1). To make the device operate in the

bistable regime, CW-light is injected in the DFB-laser. Switching from the lasing to the non-lasing state can be done by injection of a small pulse at the same side of the device as the CW-light. By injecting a pulse from the other side, the uniformity of the carrier distribution will be restored and the laser will switch on again.



Figure 1 : Schematic of principle

3. Bistability

Using static measurements, we have observed the bistability experimentally in an anti-reflection coated, $\lambda/4$ -shifted DFB-laser with a length of 400 μm provided by Alcatel-Thales III/V-labs. The laser operates at a wavelength of 1553.7 nm and we inject light with a wavelength of 1543 nm. We observe that the bistability widens with increasing current and the extinction ratio is up to 35 dB (Figure 2). For lower values of the injected current (≤ 100 mA), no bistability was observed.

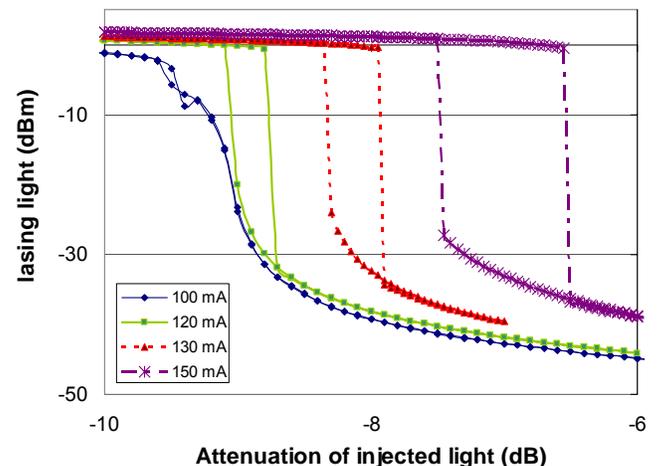


Figure 2: Measured bistability for a $\lambda/4$ -shifted DFB-laser of 400 μm and different injection currents.

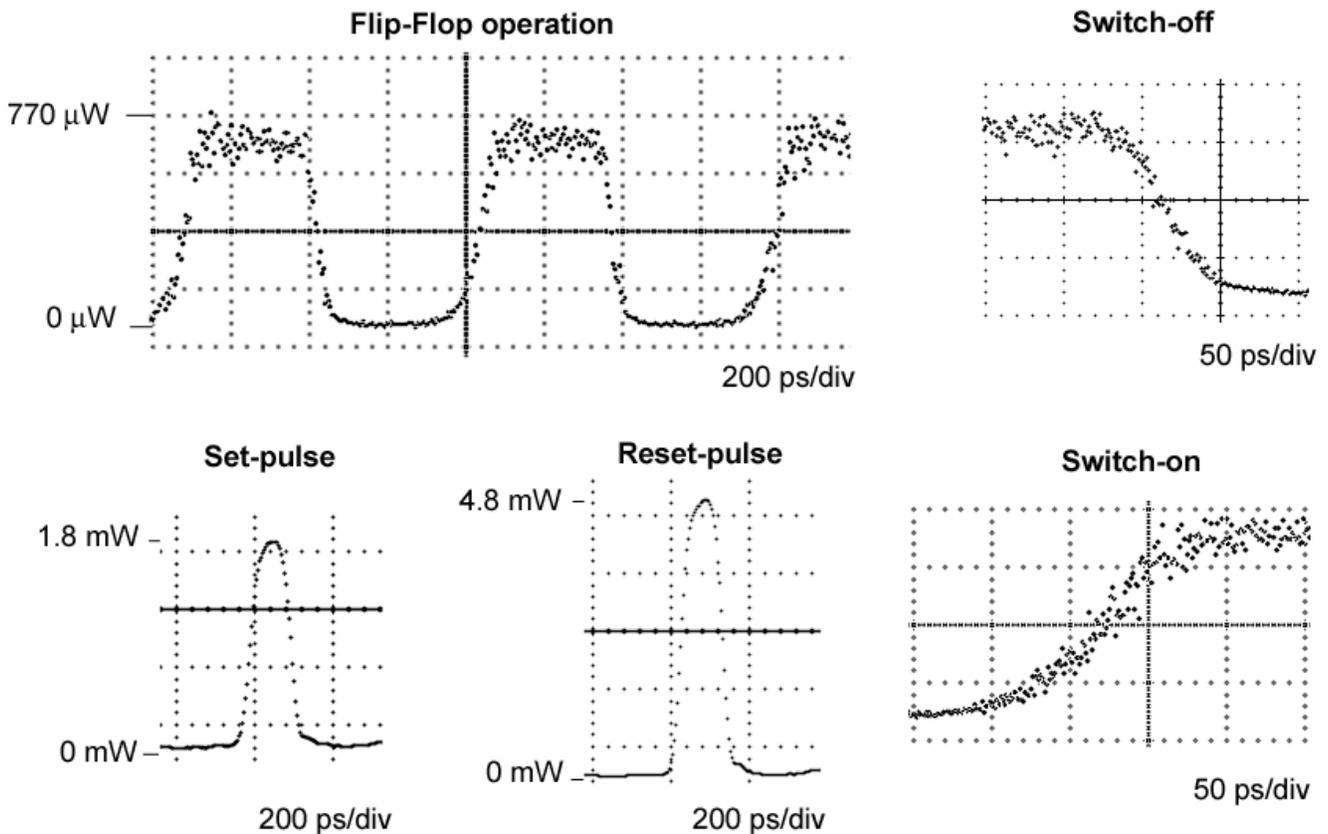


Figure 3: All-optical flip-flop operation using pulses of 100 ps with energy less than 0.5 pJ. Repetition rates up to 1.25 GHz can be obtained and the switch-on time of the laser is only 120 ps.

4. Flip-flop operation

To obtain flip-flop operation we switch between the two states of the bistability by injecting optical pulses in the device. To operate in the bistable regime, we inject CW-light of 900 μW at a wavelength of 1543 nm. The reset-pulses have an energy of 0.5 pJ and are sent at the same side as the CW-light. They will switch the laser off by disturbing the uniformity of the carrier distribution. The set-pulses on the other hand are weaker (0.2 pJ) and are sent on the other side of the device to restore the uniformity in the cavity again. We demonstrate flip-flop operation here with pulses of 100 ps length and repetition rates up to 1.25 GHz. The switch-on time of the device is 120 ps and the switch-off time 50 ps.

5. Conclusion

We demonstrated all-optical flip-flop operation in a single DFB-laser diode. Repetition rates up to 1.25 GHz can be achieved using pulses of 100 ps with less than 0.5 pJ.

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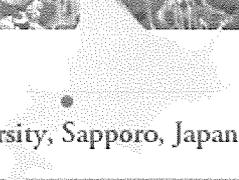
References

- [1] H.J.S. Dorren *et al.*: "Optical packet switching and buffering by using all-optical signal processing methods" *Journal of Lightwave Technology*, 21(1), 2003.
- [2] M. Takenaka and Y. Nakano: "Multimode interference bistable laser diode", *Photonics Technology Letters* 15(8), 2003
- [3] R. Clavero *et al.*: "All-optical flip-flop based on a single SOA-MZI", *Photonics Technology Letters* 17(4), 2005
- [4] K. Huybrechts *et al.*: "Proposal for an all-optical flip-flop using a single laser diode", *Photonics Technology Letters*. 20(1), 2008



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Co-chairs Message	Technical Program	Author Index	Sponsorship	Search
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- Co-chairs Message
- Technical Program
- Author Index
- Sponsorship
- Search

Author Index

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A

Abril Domingo, Evaristo J.	S-02-4	Efficient Design of Wavelength-Routed Optical Networks with Failure Protection Using Genetic Algorithms
Aguado Manzano, Juan Carlos	S-02-4	Efficient Design of Wavelength-Routed Optical Networks with Failure Protection Using Genetic Algorithms
Al Amin, Abdullah	S-07-5	Experimental Demonstration of Optical Burst Switch Prototype Equipped with Pre-Emptive Scheduler for Absolute QoS Guarantees
Albores-Mejia, A.	D-06-4	Scalable Quantum Dot Optical Switch Matrix in the 1.55µm Wavelength Range
Almeida Jr., Raul C.	P-24	An Optical Packet Switch Employing Shared Tunable Parametric Wavelength Converters
Alparslan, Onur	S-01-3	Node Pacing for Optical Packet Switching
Amemiya, Yoshiteru	D-02-4	Electric-Field Drive Optical Modulator Using Si Ring Resonator
Anantathanasarn, A.	D-06-4	Scalable Quantum Dot Optical Switch Matrix in the 1.55µm Wavelength Range
Andrioli, Nicola	P-32	Bi-directional Lightpath Provisioning in GMPLS-Controlled Optical Networks
Andrioli, Nicola	S-04-3	Reactive Re-Provisioning Heuristics for Mitigating the Impact of Traffic Pattern Variations on Multi-Layer Optical Networks
Andrioli, Nicola	S-08-2	Path Restoration Schemes in GMPLS-Controlled Translucent Networks
Aoyagi, Toshitaka	D-08-4	Coupling Mode Analysis of Self-Pulsating DFB Laser Diodes for All-Optical Signal Recovery at 40 Gbps
Aoyama, Tomonori	P-40-3	New Generation Network -Beyond Internet-
Arakawa, Shin'ichi	S-03-3	Node Pacing for Optical Packet Switching
		P-04-2: Carriers' Transport Network Based on PLZT High-Speed Optical

Arakawa, Yutaka	S-02-1	Slot Switching (OSS)
Arakawa, Yutaka	S-02-3	Fast Fault Recovery Method with Pre-Established Recovery Table for Wide Area Ethernet
Arakawa, Yutaka	S-02-5	10 GE Optical Layer Protection Evaluation Using PLZT Optical Switches
Araki, Seichiro	S-08-4	Multi-Domain ASON/GMPLS Network Operations
Asakawa, Kiyoshi	D-04-3	Design and Fabrication of Nano-Photonics-Based All-Optical Flip-Flop Switch
Azaña, Jose	D-03-3	Ultrafast Pulse Processing and Shaping Based on Long-Period Fiber Gratings for Optical Coding and Switching Applications

A B C D E F G H I J K L M N O P R S T U V W X Y Z Page Top

B

	Baek, Yongsoon	P-8	10 Channel Polymer Variable Optical Attenuator Array for Power Monitoring and Equalization in Integrated PLC ROADM Module
→	Baets, R.	D-02-3	Heterogeneous III-V/Silicon-on-Insulator Photonic Integrated Circuits
→	Baets, Roel	D-04-6	Experimental Demonstration of All-Optical Flip-Flop Operation with a Single Distributed Feedback Laser Diode
	Barman, Abhirup Das	S-06-2	Single RSOA Based ONU for RZ Symmetrical WDM PONs at 2.5 Gb/s
	Barth, Dominique	P-25	Two Cycles Routing and End to End Delay Bound in an All Optical Network
	Barton, Jonathon S.	D-01-4	Recent Progress on LASOR Optical Router and Related Integrated Technologies
	Bayart, Dominique	S-05-2	Packet Power Dynamic Range Management in Optical Packet Ring Networks
	Bergman, Keren	S-03-3	Nanophotonic Interconnection Networks for Multicore Embedded Computing Systems
	Berrettini, Gianluca	D-05-5	All-Optical Digital Processing through Semiconductor Optical Amplifiers: State of the Art and Perspectives
	Berrettini, Gianluca	S-06-2	Single RSOA Based ONU for RZ Symmetrical WDM PONs at 2.5 Gb/s
	Blow, Keith J.	D-04-5	Experimental Demonstration of SOA Based Non-Inverting Optical Memory
	Blumenthal, Daniel J.	D-01-4	Recent Progress on LASOR Optical Router and Related Integrated Technologies
	Blumenthal, Daniel J.	D-02-2	Hybrid Silicon Photonic Integrated Circuits for Optical Networking
	Bogoni, Antonella	D-04-4	Single-SOA Optical Memory Based on Coupled Fiber Ring Lasers
	Bogoni, Antonella	D-05-5	All-Optical Digital Processing through Semiconductor Optical Amplifiers: State of the Art and Perspectives
	Bogoni, Antonella	D-07-3	All-Optical Multiple Wavelength Conversion Using ASE Light and a Passive Vertical-Cavity Semiconductor Gate
	Bogoni, Antonella	P-16	The Mickey NOLM: Nonlinear All-Optical Processing Based on PM-NOLM Structures
	Bogoni, Antonella	S-06-2	Single RSOA Based ONU for RZ Symmetrical WDM PONs at 2.5 Gb/s
	Borne, Sophie	S-05-2	Packet Power Dynamic Range Management in Optical Packet Ring Networks
	Boscolo, Sonia	D-03-1	Novel Approaches in Nonlinear Optical Fibre-Based Signal Processing
	Bowers, John E.	D-01-4	Recent Progress on LASOR Optical Router and Related Integrated Technologies
	Bowers, John E.	D-02-2	Hybrid Silicon Photonic Integrated Circuits for Optical Networking